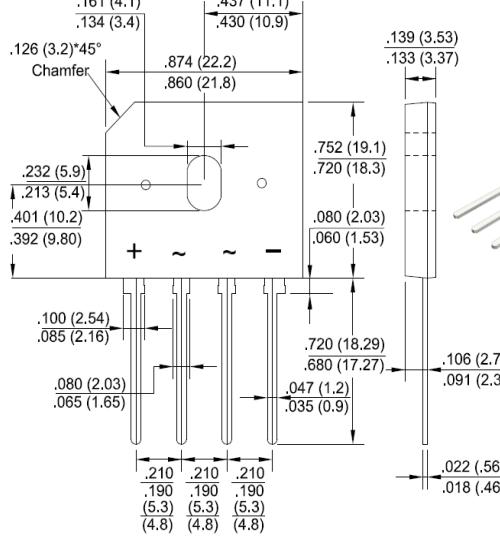


GBU6005 THRU GBU610

| Glass Passivated Bridge Rectifiers | Reverse Voltage - 50 to 1000 Volts Forward Current - 6.0 Amperes | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
|--|--|--------------|---------|--------|-------------|--------|--------|--------|------------------|------|---|------------------|----|-----|-----|-----|-----|-----|------|---|---------------------|------------------|----|----|-----|-----|-----|-----|-----|---|-----------------------------|-----------------|----|-----|-----|-----|-----|-----|------|---|--|-------------------|--|--|--|--|-----|--|--|---|---|------------------|--|--|--|--|-----|--|--|---|--|------------------|--|--|--|-------|--|--|--|------------------|---|----------------|--|--|--|-----|--|--|--|---|---|----------------|--|--|--|-----|--|--|--|----|--|----------------|--|--|--|-----|--|--|--|----|--|------------------|--|--|--|---|--|--|--|------|--------------------------------------|----------------|--|--|--|-------------|--|--|--|----|---------------------------|------------------|--|--|--|-------------|--|--|--|----|--|
| <p>Features</p> <ul style="list-style-type: none"> • Glass passivated chip • Low forward voltage drop • Ideal for printed circuit board • High surge current capability <p>Mechanical Data</p> <ul style="list-style-type: none"> • Polarity: Symbol marked on body • Mounting position: Any <p>Applications</p> <ul style="list-style-type: none"> • General purpose use in AC/DC bridge full wave rectification, for SMPS, lighting ballaster, adapter, etc. |  <p>GBU</p>  <p>Package Outline Dimensions in Inches (Millimeters)</p> | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| <p>Maximum Ratings and Electrical Characteristics</p> <p>Rating at 25°C ambient temperature unless otherwise specified.</p> <p>Single phase, half wave, 60Hz, resistive or inductive load.</p> <p>For capacitive load, derate current by 20%.</p> | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| <table border="1"> <thead> <tr> <th>Characteristic</th> <th>Symbol 符号</th> <th>GBU6005</th> <th>GBU601</th> <th>GBU602</th> <th>GBU604</th> <th>GBU606</th> <th>GBU608</th> <th>GBU610</th> <th>Unit</th> </tr> </thead> <tbody> <tr> <td>Maximum Repetitive Peak Reverse Voltage</td> <td>V_{RRM}</td> <td>50</td> <td>100</td> <td>200</td> <td>400</td> <td>600</td> <td>800</td> <td>1000</td> <td>V</td> </tr> <tr> <td>Maximum RMS Voltage</td> <td>V_{RMS}</td> <td>35</td> <td>70</td> <td>140</td> <td>280</td> <td>420</td> <td>560</td> <td>700</td> <td>V</td> </tr> <tr> <td>Maximum DC Blocking Voltage</td> <td>V_{DC}</td> <td>50</td> <td>100</td> <td>200</td> <td>400</td> <td>600</td> <td>800</td> <td>1000</td> <td>V</td> </tr> <tr> <td>Maximum Average Forward (with heatsink Note 2) Rectified Current @ T_c=100°C (without heatsink)</td> <td>I_(AV)</td> <td></td> <td></td> <td></td> <td></td> <td>6.0</td> <td></td> <td></td> <td>A</td> </tr> <tr> <td>Peak Forward Surge Current, 8.3mS Single Half Sine-Wave, Superimposed on Rated Load (JEDEC Method)</td> <td>I_{FSM}</td> <td></td> <td></td> <td></td> <td></td> <td>2.8</td> <td></td> <td></td> <td>A</td> </tr> <tr> <td>I²t Rating for Fusing (t<8.3mS)</td> <td>I²t</td> <td></td> <td></td> <td></td> <td>127.1</td> <td></td> <td></td> <td></td> <td>A²s</td> </tr> <tr> <td>Peak Forward Voltage per Diode at 3A DC</td> <td>V_F</td> <td></td> <td></td> <td></td> <td>1.0</td> <td></td> <td></td> <td></td> <td>V</td> </tr> <tr> <td>Maximum DC Reverse Current at Rated @T_J=25°C DC Blocking Voltage per Diode @T_J=125°C</td> <td>I_R</td> <td></td> <td></td> <td></td> <td>5.0</td> <td></td> <td></td> <td></td> <td>μA</td> </tr> <tr> <td>Typical Junction Capacitance per Diode (Note1)</td> <td>C_J</td> <td></td> <td></td> <td></td> <td>500</td> <td></td> <td></td> <td></td> <td>pF</td> </tr> <tr> <td>Typical Thermal Resistance to case (with heatsink (Note2))</td> <td>R_{θJC}</td> <td></td> <td></td> <td></td> <td>2</td> <td></td> <td></td> <td></td> <td>°C/W</td> </tr> <tr> <td>Operating Junction Temperature Range</td> <td>T_J</td> <td></td> <td></td> <td></td> <td>-55 to +150</td> <td></td> <td></td> <td></td> <td>°C</td> </tr> <tr> <td>Storage Temperature Range</td> <td>T_{STG}</td> <td></td> <td></td> <td></td> <td>-55 to +150</td> <td></td> <td></td> <td></td> <td>°C</td> </tr> </tbody> </table> | Characteristic | Symbol 符号 | GBU6005 | GBU601 | GBU602 | GBU604 | GBU606 | GBU608 | GBU610 | Unit | Maximum Repetitive Peak Reverse Voltage | V _{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V | Maximum RMS Voltage | V _{RMS} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V | Maximum DC Blocking Voltage | V _{DC} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V | Maximum Average Forward (with heatsink Note 2) Rectified Current @ T _c =100°C (without heatsink) | I _(AV) | | | | | 6.0 | | | A | Peak Forward Surge Current, 8.3mS Single Half Sine-Wave, Superimposed on Rated Load (JEDEC Method) | I _{FSM} | | | | | 2.8 | | | A | I ² t Rating for Fusing (t<8.3mS) | I ² t | | | | 127.1 | | | | A ² s | Peak Forward Voltage per Diode at 3A DC | V _F | | | | 1.0 | | | | V | Maximum DC Reverse Current at Rated @T _J =25°C DC Blocking Voltage per Diode @T _J =125°C | I _R | | | | 5.0 | | | | μA | Typical Junction Capacitance per Diode (Note1) | C _J | | | | 500 | | | | pF | Typical Thermal Resistance to case (with heatsink (Note2)) | R _{θJC} | | | | 2 | | | | °C/W | Operating Junction Temperature Range | T _J | | | | -55 to +150 | | | | °C | Storage Temperature Range | T _{STG} | | | | -55 to +150 | | | | °C | <p>Notes: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.</p> <p>2. Device mounted on 75mm*75mm*1.6mm Cu plate heatsink.</p> <p>3. The typical data above is for reference only</p> |
| Characteristic | Symbol 符号 | GBU6005 | GBU601 | GBU602 | GBU604 | GBU606 | GBU608 | GBU610 | Unit | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Maximum Repetitive Peak Reverse Voltage | V _{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Maximum RMS Voltage | V _{RMS} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | V | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Maximum DC Blocking Voltage | V _{DC} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | V | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Maximum Average Forward (with heatsink Note 2) Rectified Current @ T _c =100°C (without heatsink) | I _(AV) | | | | | 6.0 | | | A | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Peak Forward Surge Current, 8.3mS Single Half Sine-Wave, Superimposed on Rated Load (JEDEC Method) | I _{FSM} | | | | | 2.8 | | | A | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| I ² t Rating for Fusing (t<8.3mS) | I ² t | | | | 127.1 | | | | A ² s | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Peak Forward Voltage per Diode at 3A DC | V _F | | | | 1.0 | | | | V | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Maximum DC Reverse Current at Rated @T _J =25°C DC Blocking Voltage per Diode @T _J =125°C | I _R | | | | 5.0 | | | | μA | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Typical Junction Capacitance per Diode (Note1) | C _J | | | | 500 | | | | pF | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Typical Thermal Resistance to case (with heatsink (Note2)) | R _{θJC} | | | | 2 | | | | °C/W | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Operating Junction Temperature Range | T _J | | | | -55 to +150 | | | | °C | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| Storage Temperature Range | T _{STG} | | | | -55 to +150 | | | | °C | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |
| | <p>GBU6*-U/B-00/99-00/01 Rev. 9, 22-Apr-2019</p> | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | | |

Rating and Characteristic Curves

GBU6005 THRU GBU610

Fig. 1 - Forward Current Derating Curve

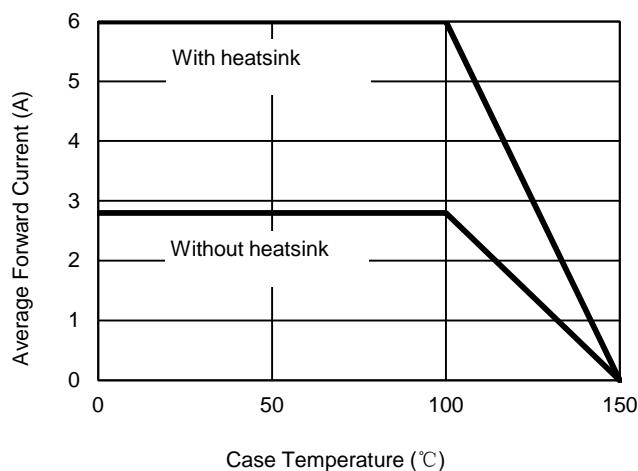


Fig. 2 - Maximum Non-Repetitive Surge Current

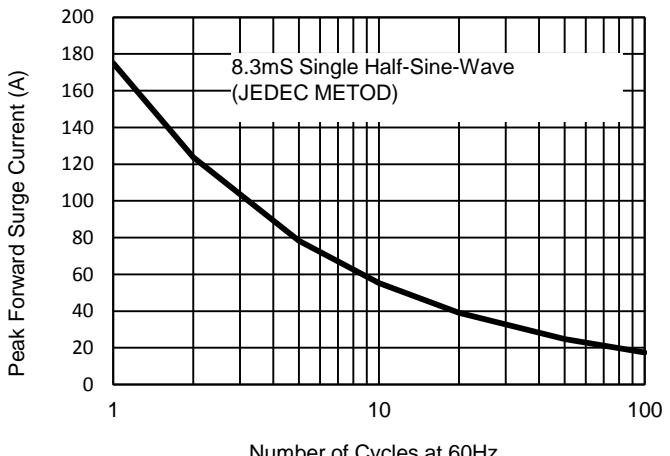


Fig. 3 - Typical Reverse Characteristics

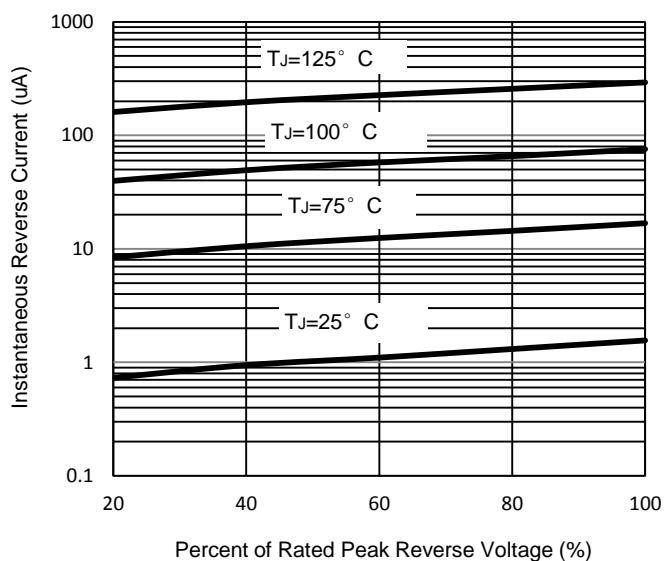


Fig. 4 - Typical Forward Characteristics

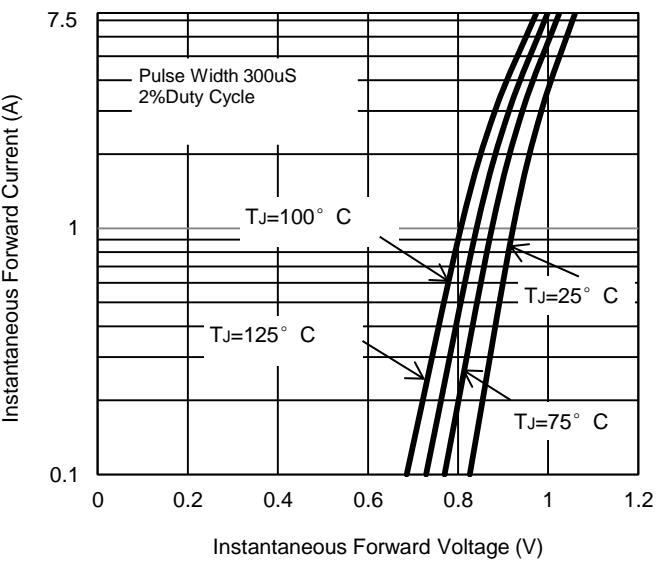
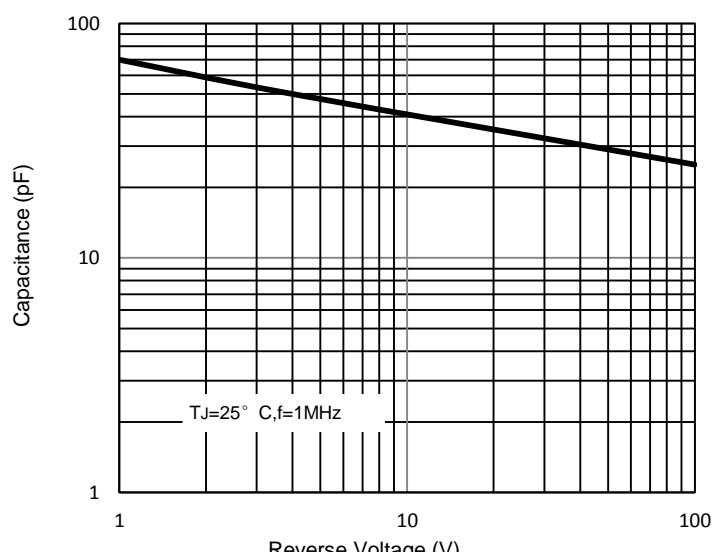


Fig. 5 - Typical Junction Capacitance



The curve above is for reference only.

